	Application No.	Applicant(s)	-
Notice of Allowability			
	09/927,863	BAMNOLKER ET A	<u>L.</u>
	Examiner	Art Unit	
	Lynette T. Umez-Eronini	1765	
The MAILING DATE of this communication apperature All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT R of the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in this or other appropriate communica IGHTS. This application is subjection.	application. If not includ tion will be mailed in due	ed course. THIS
1. This communication is responsive to <u>5/18/2004</u> .			
2. The allowed claim(s) is/are 1-6,8-23 and 31-38.			
3. The drawings filed on file) are accepted by the Examine	r.		
 4. ☐ Acknowledgment is made of a claim for foreign priority una) ☐ All b) ☐ Some* c) ☐ None of the: 1. ☐ Certified copies of the priority documents have 2. ☐ Certified copies of the priority documents have 3. ☐ Copies of the certified copies of the priority do International Bureau (PCT Rule 17.2(a)). * Certified copies not received: 	e been received. e been received in Application No	·	ation from the
Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONN THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.		ply complying with the re	quirements
5. A SUBSTITUTE OATH OR DECLARATION must be subm INFORMAL PATENT APPLICATION (PTO-152) which give			OTICE OF
6. CORRECTED DRAWINGS (as "replacement sheets") mus	st be submitted.		
(a) ☐ including changes required by the Notice of Draftspers	son's Patent Drawing Review (P	TO-948) attached	•
1) ☐ hereto or 2) ☐ to Paper No./Mail Date		·	
(b) ☐ including changes required by the attached Examiner's Paper No./Mail Date	s Amendment / Comment or in th	e Office action of	
Identifying indicia such as the application number (see 37 CFR 1 each sheet. Replacement sheet(s) should be labeled as such in t	.84(c)) should be written on the dra	awings in the front (not the	back) of
7. DEPOSIT OF and/or INFORMATION about the depo attached Examiner's comment regarding REQUIREMENT	sit of BIOLOGICAL MATERIA	L must be submitted.	Note the
Attachment(s) 1. Notice of References Cited (PTO-892)	5. Notice of Informa	al Patent Application (PT	O-152)
2. Notice of Draftperson's Patent Drawing Review (PTO-948)	6. 🛛 Interview Summ		
Information Disclosure Statements (PTO-1449 or PTO/SB/0 Page No. (Mail Date) Page 1 No. (Mail Date) Page 2 No. (Mail Date)	Paper No./Mail 08), 7. ☐ Examiner's Ame		
Paper No./Mail Date 4. Examiner's Comment Regarding Requirement for Deposit	8. X Examiner's State	ement of Reasons for Allo	owance
of Biological Material	9. Other		
	ei i P	NADINE G. NORTO	ON XAMINER

U.S. Patent and Trademark Office PTOL-37 (Rev. 1-04) Application/Control Number: 09/927,863

Art Unit: 1765

EXAMINER'S AMENDMENT

1. An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

Authorization for this examiner's amendment was given in a telephone interview with Paul E. Rauch on June 2, 2004.

The application has been amended as follows:

In claim 8, delete "7" and insert --1--.

In claim 15, delete "7" and insert --1--.

2. The following is an examiner's statement of reasons for allowance: Applicants have presented persuasive arguments in Remarks (pages 2-4) of amendment filed 5/18/2004, which show:

As to claims 1-7 and 8-23, the prior art of record, taken either alone or in combination, fails to disclose or render obvious a method of forming a semiconductor structure comprising a last portion of the oxide layer is etched with an oxide etching chemistry, which comprises CF₄ and CHF₃ and that is different from the nitride etching chemistry, in combination with the rest of the limitation of the above claims.

As to claims 31-38, the prior art of record, taken ether alone or in combination, fails to disclose or render obvious a method of forming a semiconductor structure comprising a last portion of the oxide layer is etched with an oxide etching chemistry

Application/Control Number: 09/927,863

Art Unit: 1765

that is different from the nitride etching chemistry that comprises a fluorinated hydrocarbon, oxygen, and an inert gas selected from the group consisting of neon, argon, krypton, xenon, and combinations thereof, in combination with the rest of the limitation of the above claims.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Lynette T. Umez-Eronini whose telephone number is 571-272-1470. The examiner is normally unavailable on the First Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nadine Norton can be reached on 571-272-1465. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Itue

June 1, 2004

NADINE G. NORTON SUPERVISORY PATENT EXAMINER